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Question Paper Code: 21442

B.E./B.Tech. DEGREE EXAMINATIONS, NOVEMBER/DECEMBER 2023.

Second Semester

Electrical and Electronics Engineering

PH 3202 — PHYSICS FOR ELECTRICAL ENGINEERING

(Regulations 2021)

Time: Three hours

Maximum: 100 marks

Answer ALL questions.

PART A — $(10 \times 2 = 20 \text{ marks})$

- 1. Define Dipole moment and Polarization phenomenon.
- 2. Give examples of capacitor materials.
- 3. Give the expression for thermal conductivity of a solid.
- 4. Explain the concept of holes in semiconductors.
- 5. Draw the Energy band diagram of indirect band gap semiconductors.
- 6. Illustrate the Hall effect in a P-type semiconductor bar with diagram.
- 7. Explain the optical process in quantum wells.
- 8. Name any two non-linear optical phenomena.
- 9. What is quantum confinement?
- 10. Explain quantum resistance and conductance.

PART B — $(5 \times 16 = 80 \text{ marks})$

11. (a) Derive expressions for Electronic Polarization and Ionic Polarization in a dielectric material. (16)

Or

(b) Show how microscopic property of atomic polarizability is related to macroscopic dielectric constant by obtaining expressions for Lorentz internal field and Clausius-Mossotti equation. (16)

12.	(a)	(i)	Derive expressions for density of energy states in a solid.	(8)
		(ii)	Explain how electrons behave in a periodic potential in a solid.	(8)
			Or	
	(b)		sify magnetic materials and explain diamagnetic, Paramagnetic omagnetic effects.	and (16)
13.	(a)	resu	ve carrier concentration in an intrinsic semiconductor and from lts, obtain an expression for density of electrons an N- iconductor.	type (16)
			Or	
	(b)		ain the variation of carrier concentration with temperature pe semiconductor using suitable theory and diagram.	in a (16)
14.	(a)		the classification of Optical materials and explain the different processes in semiconductors.	rent (16)
			\mathbf{Or}	
	(b)	Expl	ain Electro-Optic Modulators and switching devices in detail.	(16)
15.	(a)		ain the Single electron phenomena and the working of Si cron Transistor.	ngle (16)
			Or	
	(b)	Expl	ain the properties and applications of Carbon nanotubes.	(16)
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